



## T16M10T800HD(LS)

# TRIACS SILICON BIDIRECTIONAL THYRISTORS

### TRIACS 16 AMPERES RMS 800V VOLTS

#### **FEATURES**

- 3Q technology for improved noise immunity
- · High junction operating temperature capability
- High voltage capability
- Triggering in three quadrants only
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

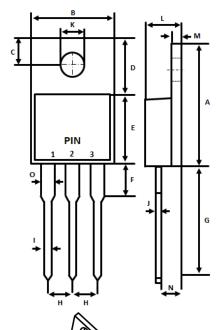
#### **APPLICATIONS**

- Applications subject to high temperature
- · Heating and cooking appliances
- Electronic thermostats (heating and cooling)
- High power motor controls e.g. washing machines and vacuum

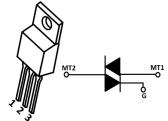
#### **MECHANICAL DATA**

- Package: TO-220AB Insulated
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 2.15 grams (Approximate)

### TO-220AB Insulated



TO-220AB Insulated			
DIM.	MIN.	MAX	
Α	14.40	15.20	
В	9.65	10.67	
С	2.54	3.43	
D	5.84	6.86	
Е	8.26	9.28	
F		6.35	
G	12.7	14.73	
Н	2.29	2.79	
I	0.51	1.14	
J	0.30	0.64	
K	3.53Ø	4.09Ø	
L	3.56	4.83	
М	1.14	1.40	
N	2.03	2.92	
0	1.14	1.37	
All dimensions in millimeter			



PIN ASSIGNMENT			
1	Main terminal 1		
2	Main terminal 2		
3	Gate		

#### **MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at +25°C ambient temperature unless otherwise specified.

PARAMETER	SYMBOL	VALUE	UNIT
Peak repetitive off-state voltage (T <sub>J</sub> = -40 to +150°C, full sine wave, 50 to 60Hz, gate open)	V <sub>DRM</sub> V <sub>RRM</sub>	800 800	V
On-stage RMS current (full sine wave, T <sub>C</sub> = +125°C)	I <sub>T(RMS)</sub>	16	Α
Peak non-repetitive surge current (full sine wave @ 50Hz, T <sub>J</sub> = +25°C)	I <sub>TSM</sub>	160	А
Circuit fusing consideration (t = 10ms)	l <sup>2</sup> t	128	A <sup>2</sup> s
Operating junction temperature range	TJ	-40 to +150	°C
Storage temperature range	T <sub>STG</sub>	-40 to +150	°C

#### Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



### **OFF CHARACTERISTICS**

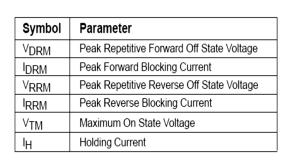
PARAMETER		SYMBOL	MAX	UNIT
Peak repetitive forward or reverse blocking current	T <sub>J</sub> = +25°C	Idrm Irrm	5	μA
$(V_{AK} = rated V_{DRM} and V_{RRM}, gate open)$	T <sub>J</sub> = +150°C		2	mA

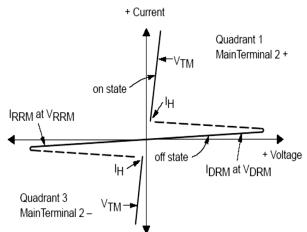
### **ON CHARACTERISTICS**

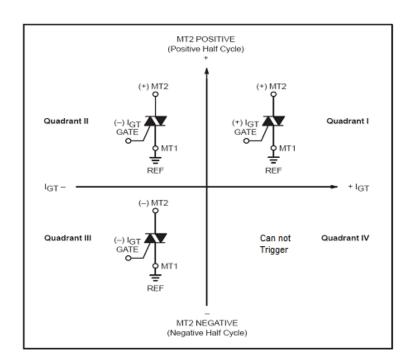
PARAMETER	SYMBOL	MAX	UNIT
Peak forward on-state voltage (I <sub>TM</sub> = 16A @ T <sub>J</sub> = +25°C)	V <sub>ТМ</sub>	1.55	V
Gate trigger current ( $V_{AK} = 12V$ , $R_L = 100\Omega$ )	Іст1 Іст2 Іст3	10	mA
Gate trigger voltage ( $V_{AK} = 12V$ , $R_L = 100\Omega$ )	V <sub>GT</sub> 1 V <sub>GT</sub> 2 V <sub>GT</sub> 3	1.3	V
Holding current ( $V_{AK} = 12V$ , $R_L = 100\Omega$ )	I <sub>Н</sub> 1 Iн3	15	mA
Latching current ( $V_{AK} = 12V$ , $R_L = 100\Omega$ )	IL1 IL2 IL3	25 30 25	mA

### **DYNAMIC CHARACTERISTICS**

PARAMETER	SYMBOL	MIN.	UNIT
Critical rate of rise of off-stage voltage ( $V_{AK} = 67\%$ rated $V_{DRM}$ , exponential waveform, gate open, $T_J = +125$ °C)	dv/dt(s)	40	V/µs
Critical rate of rise of on-state current (V <sub>DRM</sub> = maximum V <sub>DRM</sub> , T <sub>J</sub> = +125°C)	di/dt(s)	60	A/µs
Rate of change of commutating current $(V_D = 400V, 10V/\mu s, T_J = +125^{\circ}C)$	di/dt(c)	3.0	A/ms

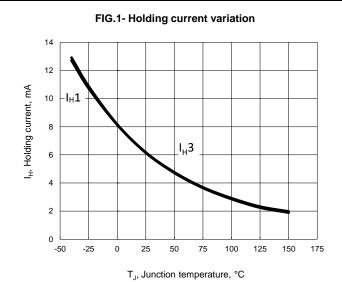


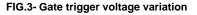




All polarities are reference to MT1, with in-phase signal (using standard AC lines) quadrants I and III are used.







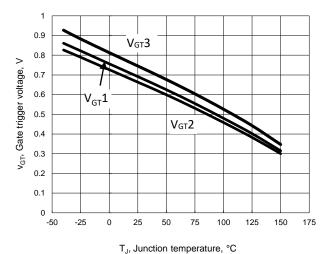


FIG.5- On-state characteristics

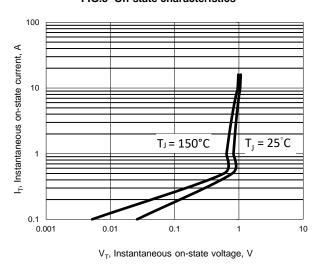
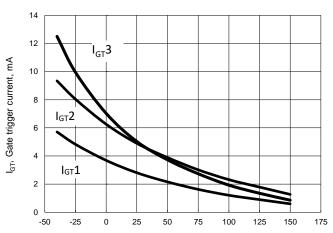
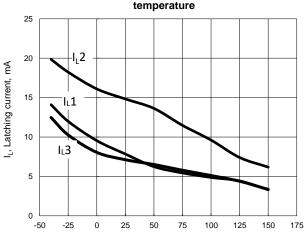


FIG.2- Gate trigger current variation



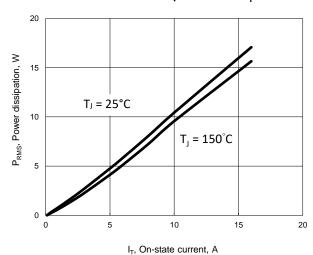
T<sub>J</sub>, Junction temperature, °C

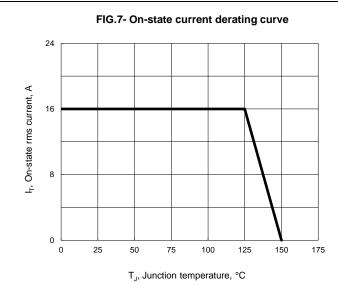
FIG.4- Typical latching current versus junction temperature



T<sub>J</sub>, Junction temperature, °C

FIG.6- Power dissipation versus I<sub>T</sub>



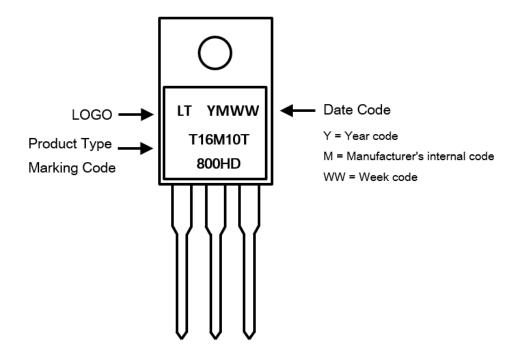




### **Ordering Information:**

Part Number	Packago	Packing	
Fait Number	Package	Qty.	Carrier
T16M10T800HD	TO-220AB Insulated	50pcs	Tube

### **Marking Information:**





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